

## **1200V SiC Power MOSFETs**



#### **Features**

- SiC MOSFET technology
- High blocking voltage with low RDS(on)
- High-speed switching with low capacitances
- Avalanche capability
- Halogen-free, "green" deviceEpoxy meets UL 94 V-0
- Epoxy meets UL 94 V-0 Flammability Rating
- Lead-free finish/RoHS compliant



## **Benefits**

Ideal for industrial applications, SICW080N120Y-BP and SICW080N120Y4 use SiC technology to provide twice the electron saturation velocity and ten times the dielectric breakdown field strength to deliver a high-powered component in a small package.

## **Applications**







Charging

Industrial

Renewable Energy

# 1200V SiC N-CHANNEL Power MOSFETs

SICW080N120Y-BP SICW080N120Y4 Package: TO-247-3 Package: TO-247-4



MCC'S NEW 1200V <u>SILICON</u>
<u>CARBIDE MOSFETS</u> ARE FAST,
RUGGED, AND CAPABLE.





# 1200V SiC N-Channel Power MOSFETs





SICW080N120Y-BP

SICW080N120Y4

### **Parametrics & Datasheets:**

Product	Туре	Package	Drain- source Voltage (VDS)	Gate Source Voltage (VGSmax)	RDS(ON) MAX	Continuous Drain Current (ID)	Datasheet
SICW080N120Y-BP	SiC MOSFETs	TO-247-3	1200V	-8V/ +22V	0.085	38A	<u>Datasheet</u>
SICW080N120Y4	SiC MOSFETs	TO-247-4	1200V	-8V/ +22V	0.085	39A	<u>Datasheet</u>

## **Applications:**



- High-voltage DC/DC Converters
- Battery Chargers
- Industrial Chargers
- Off Board Chargers



- Power Factor Correction
- AC-DC High-Power SMPS
- Motor Drivers



- Solar Inverters
- Energy Storage
- Wind Turbines

CONTACT MCC
TO REQUEST A SAMPLE

